Accepted Manuscript

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PII: S0925-9635(15)30050-9

DOI: doi: 10.1016/j.diamond.2015.10.001

Reference: DIAMAT 6472

To appear in: Diamond & Related Materials

Received date: 7 June 2015 Revised date: 26 August 2015 Accepted date: 1 October 2015



Please cite this article as: S.H. Michaelson, M. Chandran, A. Hoffman, Evidence for D_2 dissociative chemisorption and electron affinity changes of bare and ion beam damaged polycrystalline diamond surfaces, *Diamond & Related Materials* (2015), doi: 10.1016/j.diamond.2015.10.001

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Evidence for D₂ dissociative chemisorption and electron affinity changes of bare and

ion beam damaged polycrystalline diamond surfaces

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Abstract

Polycrystalline diamond films surfaces were in-situ annealed and 1 keV Ar⁺ implanted

to achieve bare and ion beam damaged surface. These films were exposed to D₂ gas

and C-D bonding was monitored by high resolution electron energy loss spectroscopy.

Our experimental results clearly show the preferential dissociative D2 adsorption onto

the low hybridized carbon (sp/sp²) states with activation temperature as low as at RT.

Ultra-violet photoelectron spectroscopy provides clear evidence of electron affinity

decrease of bare and damaged diamond surface after exposure to molecular deuterium

at RT.

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